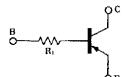


# COMPOUND TRANSISTOR AN1F4Z

# on-chip resistor PNP silicon epitaxial transistor For mid-speed switching

#### **FEATURES**

 On-chip bias resistor (R<sub>1</sub> = 22 kΩ)



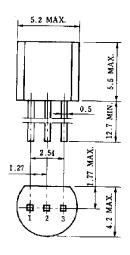
Complementary transistor with AA1A4Z

### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vcво	-60	V
Collector to emitter voltage	VCEO	-50	V
Emitter to base voltage	V <sub>EBO</sub>	<b>-</b> 5	V
Collector current (DC)	Ic(DC)	-100	mA
Collector current (Pulse)	Ic(pulse) *	-200	mA
Total power dissipation	Рт	250	mW
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

<sup>\*</sup> PW  $\leq$  10 ms, duty cycle  $\leq$  50 %

#### PACKAGE DRAWING (UNIT: mm)



Electrode Connection

Emitter EIAJ : SC~43B
 Collector JEDEC : TO 92
 Base IEC : PA33

#### **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = -50 V, IE = 0			-100	nA
DC current gain	h <sub>FE1</sub> **	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -5.0 \text{ mA}$	135	280	600	-
DC current gain	h <sub>FE2</sub> **	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -50 \text{ mA}$	100	200		-
Collector saturation voltage	V <sub>CE(sat)</sub> **	$Ic = -5.0 \text{ mA}, I_B = -0.25 \text{ mA}$		-0.06	-0.2	V
Low level input voltage	VIL **	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -100 \ \mu\text{A}$		-0.57	-0.5	V
High level input voltage	V <sub>IH</sub> **	$V_{CE} = -0.2 \text{ V}, \text{ Ic} = -5.0 \text{ mA}$	-3.0	-1.1		V
Input resistance	R <sub>1</sub>		15.4	22	28.6	kΩ
Turn-on time	ton	$Vcc = -5.0 \text{ V}, \text{ RL} = 1.0 \text{ k}\Omega$			0.2	μs
Storage time	tstg	$V_1 = -5.0 \text{ V}, \text{ PW} = 2.0 \ \mu\text{s}$			5.0	μs
Turn-off time	toff	duty cycle≤2 %			6.0	μs

<sup>\*\*</sup> Pulse test PW ≤ 350 μs, duty cycle ≤ 2 %

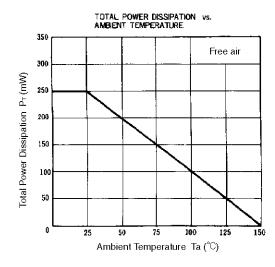
#### **hfe CLASSIFICATION**

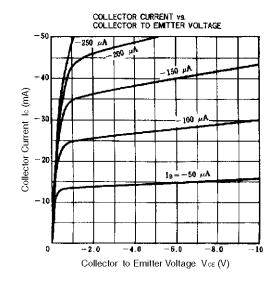
	T	T	Г
Marking	Q	Р	K
h <sub>FE1</sub>	135 to 270	200 to 400	300 to 600

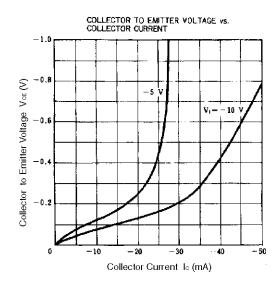
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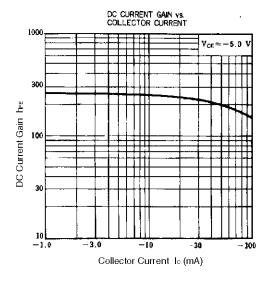


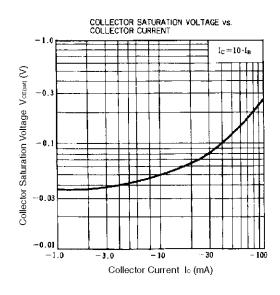
## TYPICAL CHARACTERISTICS (Ta = 25°C)

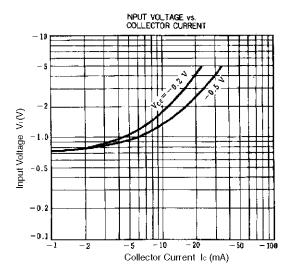


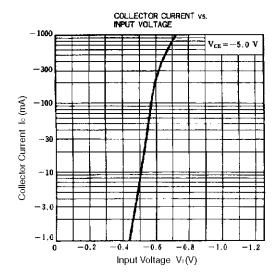


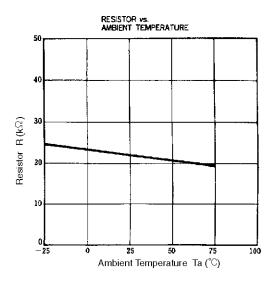












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